

Using electron irradiation to probe iron - based superconductors

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High energy electron irradiation is an efficient way to create vacancy-interstitial Frenkel pairs in crystal lattice, thereby inducing controlled non-magnetic point - like scattering centers. In combination with London penetration depth and resistivity measurements, the irradiation was particularly useful as a phase - sensitive probe of the superconducting order parameter in iron - based superconductors lending strongest support to sign - changing $s_{\pm}$ pairing. Here we review the key results on the effect of electron irradiation in iron-based superconductors.

I. INTRODUCTION

Due to the unconventional pairing mechanism and relatively high superconducting transition temperatures, T_c , iron - based superconductors (FeSC) remain in the focus of research activity even a decade after their discovery [1, 2]. Large body of experimental and theoretical works revealed a vast diversity of related compounds unified by the multi-band superconductivity and proximity to, or direct coexistence, with long - range magnetism. It is impossible to provide a comprehensive list of references here and we only give some key review articles on basic properties and models [3–33] as well as applications [34–38]. Some of key contributions come from the studies of the effect of controlled disorder induced by MeV - energy range electron irradiation. These relativistic electrons have enough energy to create vacancy - interstitial Frenkel pairs, but not too much energy to induce (undesirable) extended cascades of secondary defects produced by heavier particles, such as protons and α -particles, or columnar tracks produced by heavy ions of GeV energy [39, 40]. While the superconducting energy gap and the critical temperature of an isotropic single - band s-wave superconductors are insensitive to nonmagnetic disorder (Anderson theorem) [41, 42], multi-gap, anisotropic gaps and different gap symmetries are quite sensitive to such disorder, each with fairly unique signature in the behavior of thermodynamic and transport properties [43–51]. Contrary to the high - temperature cuprates in which a single-gap d-wave superconducting state is firmly established [52], several candidates of pairing symmetry are discussed for FeSCs due to multiple sheets of the Fermi surface supporting nesting and itinerant magnetism [6, 14]. Among them, there are two dominant scenarios for superconducting “glue”, - spin fluctuations (repulsive interaction) and orbital fluctuations (attractive interaction). The former predicts the state that requires the sign-change between different sheets of the Fermi surface ($s_{\pm}$ pairing) [6], the other predicts

no sign change (s_{++} pairing) [45, 46]. Unlike high - T_c cuprates where direct order parameter phase - sensitive experiments have proven d -wave state, similar methods cannot be applied to FeSCs due to complex multi-band electronic band structure. Some more complicated and difficult phase sensitive techniques (e.g. quasiparticle interference in STM measurements) were developed, but they are limited by surface quality and other issues related to tunneling. The alternative, based on the effects of a controlled non-magnetic disorder to distinguish $s_{\pm}$ and s_{++} pairing states, were suggested [47, 49] and implemented [39, 40]. Traditionally, effect of any irradiation on superconductors was assessed by measuring the change of T_c , critical current and, sometimes, upper critical field. This is insufficient since the low-temperature quasiparticles to examine pairing mechanism need to be studied upon irradiation. Specific heat, thermal conductivity and London penetration depth are the direct probes that should be used in addition to other measurements. Indeed, the electron irradiation combined with London penetration depth measurement was used as an effective phase-sensitive tool to reveal superconducting gap structure of several iron - based superconductors. For examples, the T - linear dependence of London penetration depth of isovalently substituted $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ was changed to exponential - like dependence using the 2.5 MeV electron irradiation, suggesting that the nodes are of accidental type and lifted upon irradiation [39]. Another example is $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ that shows the evolution of the gap structure across the superconducting “dome”, particularly near $x = 0.8$ [40]. In this review article, we summarize the key findings in studies of the effect of electron irradiation in iron - based superconductors. We limit our attention to superconductors derived upon substitution from BaFe_2As_2 and SrFe_2As_2 (referred in the following as 122 compounds).

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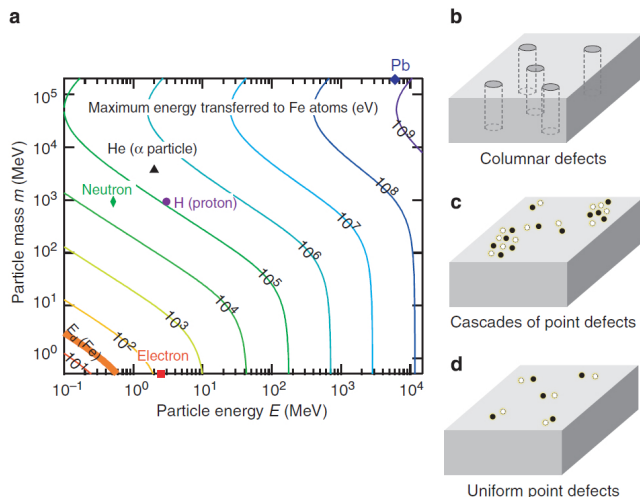


FIG. 1. (Color online) (a) Particle energy diagram of various energetic particles used for irradiation. (b, c, d) Different types of defects produced by diverse irradiation techniques. Reprinted with permission from Nature Communications, Ref. 39, copyright Macmillan Publishers Ltd.

II. EXPERIMENTAL

A. Using irradiation to induce structural disorder

Apart from plastic deformation, perhaps the most common way to introduce controlled disorder in solid samples is chemical substitution. Indeed, many such studies were conducted in high - T_c cuprates [53] and FeSCs [29]. However, the substitution changes not only the scattering but also electronic band structure, chemical potential, lattice parameters, and so on. [29, 53]. The alternative, technically more involved, way is the irradiation with energetic particles such as heavy-ions, protons, α - particles, neutrons, and electrons. The structure of the resultant disorder depends on the type of irradiation based on mass, charge and energy of the particles used [54]. Different types of irradiation produce more desirable results depending on the goals. For example, some types of heavy-ion irradiation produce columnar defects [55–57], which play very prominent role in vortex physics of layered materials, but are very difficult to analyze in terms of scattering centers. Yet, early experiments with heavy-ion irradiation in FeSCs have shown a strong violation of the Anderson theorem with saturating behavior of low-temperature London penetration depth, providing firm experimental support for multi-band $s_{\pm}$ pairing [58–60]. Proton [61–64], α -particle [65], and neutron irradiation were also used in iron - based superconductors. While the results qualitatively indicate multi-band pairing, it is hard to achieve quantitative agreement due to difficulty of analyzing cascades or clusters of defects produced by these types of irradiation. A more detailed systematic investigation of the connection between the size of the defects and T_c suppression rate was done the-

oretically in Ref. 66.

Thanks to their small mass and large charge, electrons can be accelerated to relativistic speeds in a highly controlled way using relatively compact Van der Graaf type “pellettron” accelerators. The effects of such irradiation on different systems, particularly metals and their compounds, was studied in great detail over more than half a century (See Refs. 54 and 67). Some MeV range electrons produce point-like defects with minimal impact on the material itself. The large penetration depth of electrons allows homogeneous damage of fairly thick samples (tens of μm). Following Mott’s work in 1929 [67], Damask *et al.* conducted analysis of the energy transfer from an accelerated particle smashing into the crystal lattice and found that only electrons with energies of 1–10 MeV produce point-like defects in form of interstitial ions and vacancies (Frenkel pairs) that form perfect scattering centers [54]. The energy transferred to an ion due to head-on collision by the particle of rest mass m and kinetic energy, E , is shown in Fig. 1. The ion displacement energy needed to create a Frenkel pair is typically in the range of 10–50 eV, so it is clear from Fig. 1 that only electrons would produce such individual defects. Higher energy/mass particles lead to secondary impacts resulting in cascades. The interstitials are more mobile and migrate to various “sinks”, such as dislocations, grain boundaries and surfaces leaving metastable, but robust population of vacancies behind. The studies reviewed in this article were conducted using the 2.5 MeV electron irradiation which is known to generate point-like disorders in metals and compounds.

B. Low -temperature electron irradiation

Electron irradiation reviewed in this article was conducted at SIRIUS facility operated by Laboratoire des Solides Irradiés at École Polytechnique, Palaiseau, France. Its main elements are a pellettron type accelerator made by National Electrostatics Corporation (Wisconsin, USA) and a closed cycle cryo-cooler to maintain liquid hydrogen for cooling the sample. This cooling is required to efficiently channel the heat produced upon collisions between electrons and ions, and to prevent vacancy-interstitial on-site recombination. With a calculated head-on collision displacement energy for Fe ions of 22 eV and a cross section to create Frenkel pairs in BaFe_2As_2 at 2.5 MeV of 115 barn, a dose of 1 C/cm² result in about 0.07% of the defects per iron site. Similar numbers were obtained for other ion sites with cross - sections for Ba and As being 105 and 35 barn, respectively. The electron irradiation was conducted in liquid hydrogen at 22 K, and recombination of the vacancy-interstitial pairs upon warming up to room temperature varies depending on compounds, but in general 20 - 30 %, as measured directly from the decrease of residual resistivity [68]. After initial annealing, the defects remained stable for most of crystals, but some compounds show

gradual slow annealing over the time (months).

C. Controlled disorder as a phase sensitive probe

In most previous cases, only the suppression of T_c with increased disorder was studied. When measurements of T_c as a function of disorder are combined with measurement of London penetration depth, a phase-sensitive nature of impurity scattering enables distinguishing different scenarios for the superconducting pairing. This combination of measurements was used to identify accidental character of nodes in iso-electron substituted $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ [39] and $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$ [69]. The concomitant suppression of T_c and closing of gap nodes in penetration depth study landed a strong support to $s_{\pm}$ pairing. More recently, the same idea was used to verify evolution of superconducting gap structure with composition in hole-doped $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ [40].

For the unconventional superconductors, one of the important aspects of the impurity effects is to mix gaps on different parts of the Fermi surface and thereby smear out the momentum dependence [70]. In the case of superconducting gap with symmetry protected nodes such as d-wave, this averaging mechanism leads to the suppression of the gap amplitude and creation of nodal quasiparticles. In penetration depth measurements this results in cross-over from T -linear temperature dependent penetration depth $\Delta\lambda(T)$ in clean limit to a T^2 dependence in dirty case. In addition to this, the sign change in the order parameter gives rise to impurity-induced Andreev bound states, which lead to additional quasiparticle excitations [71]. Such pair-breaking effects of nonmagnetic impurities have been observed, for example, in Zn-doped $\text{YBa}_2\text{Cu}_3\text{O}_7$ in the bulk measurements of magnetic penetration depth, where the T -linear temperature dependence in the clean-limit d-wave superconductivity gradually changes to a T^2 dependence at low temperatures with increasing Zn concentrations [72].

It is convenient to characterize the experimental data of low-temperature penetration depth using a power law function $\Delta\lambda(T) = A + BT^n$. In the above example of superconductors with symmetry imposed line nodes, the exponent n varies with increased disorder in the range between $n = 1$ (clean limit) and $n = 2$ (dirty limit). For fully gapped s-wave superconductors, $\Delta\lambda(T)$ shows exponential T -dependence which can be described as a high power-law behavior $n > 3$, but $n = 2$ when it is in dirty limit.

In sharp contrast, when the nodal positions are not symmetry protected, as in the nodal s-wave case, the averaging mechanism of impurity scattering can displace the nodes, and at a certain critical impurity concentration the nodes may be lifted if intraband scattering dominates [70], eliminating the low-energy quasiparticle excitations. In power law analysis of the penetration depth data this crossover would lead to exponent n acquiring values $n > 2$. In the fully gapped state af-

ter lifting of node, we have two cases in the multiband superconductors. If the signs of the order parameter on different bands are opposite, residual interband scattering can give rise to midgap Andreev bound states localized at nonmagnetic impurities that can contribute to the low-energy excitations, provided that the concentration of impurities is sufficient to create such states. If there is no sign change, the gap and T_c will be independent of disorder at some high rate impurity/defect scattering: since no Andreev states will be created, no significant change of the low-energy excitations is expected. Indeed, such a difference between nodal sign-changing $s_{\pm}$ and sign-preserving s_{++} cases has been theoretically suggested by the recent calculations for multiband superconductivity, considering the band structure of FeSCs [49]. Therefore, studying effects of impurity/defects on the gap nodes and low-energy excitations can be used as a powerful probe for the pairing symmetry of superconductors.

D. London penetration depth

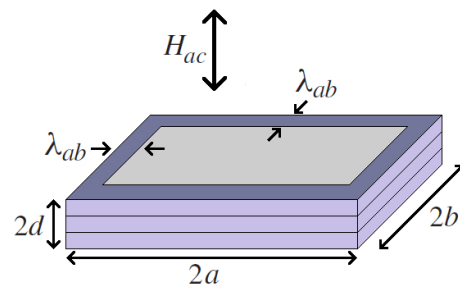


FIG. 2. (Color online) Typical sample dimension for measurement of in-plane penetration depth λ_{ab} . $2a \times 2b \times 2d \approx 500\mu\text{m} \times 500\mu\text{m} \times 50\mu\text{m}$. The ac magnetic field of H_{ac} (~ 20 mOe) is produced by TDR coil.

The London penetration depth of FeSCs has been measured using a variety of techniques such as muon-spin rotation (μSR) [73–75], frequency-dependent conductivity [76, 77], microwave cavity perturbation [78–80], mutual inductance [81], magnetic force and superconducting quantum interference device (SQUID) microscopy [82, 83], measurements of the first critical field using either global [84, 85] or local probes [86, 87], Nitrogen-vacancy center in diamond magnetometry [88], and the self-oscillating tunnel-diode resonator (TDR) [84, 89–91]. There are pros and cons for each method. The most important advantage of the tunnel diode resonator (TDR) technique is that it provides the highest resolution of London penetration depth: sub- $\text{\AA}$ for sub-mm size sample. Since the technical details are available from the previous review articles [92–94], here we briefly describe some of key aspects of this technique.

The tunnel diode resonator (TDR) is a self-oscillating tank circuit that resonates at its fundamental frequency ($f_0 = \frac{1}{2\pi\sqrt{L_0C}}$). In Ames Laboratory and other research

labs, the researchers were able to make the TDR circuit ($f_0 \cong 14$ MHz) with high stability of 1 part per 10^9 [93]. When a non-magnetic conducting sample is inserted into a TDR coil, it induces the change in frequency (Δf). In case of a finite size sample with magnetic susceptibility (χ), the change of frequency can be described as

$$\Delta f = -\frac{f_0}{2} \frac{V_s}{V_c} 4\pi\chi \quad (1)$$

where V_s and V_c are the volumes of sample and TDR coil. For a finite size sample of rectangular slab, the magnetic susceptibility (χ) can be written as

$$-4\pi\chi = \frac{1}{1-N} \left[1 - \frac{\lambda_{ab}}{R} \tanh\left(\frac{R}{\lambda_{ab}}\right) \right] \quad (2)$$

$$\cong \frac{1}{1-N} \left[1 - \frac{\lambda_{ab}}{R} \right], \text{ if } R \gg \lambda_{ab}. \quad (3)$$

Here R is the effective dimension and N is a demagnetization factor. For a rectangular slab with dimensions of $2a \times 2b \times 2d$ (Fig. 2), R can be approximated [94] as

$$R \cong \frac{\omega}{2 \left[1 + \left(1 + \left(\frac{2d}{\omega} \right)^2 \right) \arctan\left(\frac{\omega}{2d}\right) - \frac{2d}{\omega} \right]} \quad (4)$$

with $\omega \approx \frac{2ab}{a+b}$. Combining equations 1 and 3, the relation between Δf and λ_{ab} is obtained as

$$\Delta f = \frac{f_0}{2} \frac{V_s}{V_c} \frac{1}{1-N} \left[1 - \frac{\lambda_{ab}}{R} \right] \quad (5)$$

$$= G \left[1 - \frac{\lambda_{ab}}{R} \right] \quad (6)$$

where $G (= \frac{f_0}{2} \frac{V_s}{V_c} \frac{1}{1-N})$ is a geometric calibration constant that can be directly measured by pulling the sample out of the coil. Thus, the variation of penetration depth ($\delta\lambda_{ab}$) from T_{min} to T is

$$\delta\lambda_{ab} = \lambda_{ab}(T) - \lambda_{ab}(T_{min}) \quad (7)$$

$$= \frac{R}{G} (\Delta f(T_{min}) - \Delta f(T)). \quad (8)$$

Based on equation 8, one can measure the change in London penetration depth ($\delta\lambda_{ab}$) from the change in the frequency. When a sub-mm scale sample is used, the a part per billion resolution of a TDR frequency can be converted to sub-Å resolution in λ_{ab} .

III. EFFECT OF ELECTRON IRRADIATION ON THE 122 COMPOUNDS

A. Materials

The FeSCs in the 122 family share several common characteristics. One of them is ubiquitous appearance of superconductivity with highest T_c near the edge of domain of long range magnetic ordering in the phase

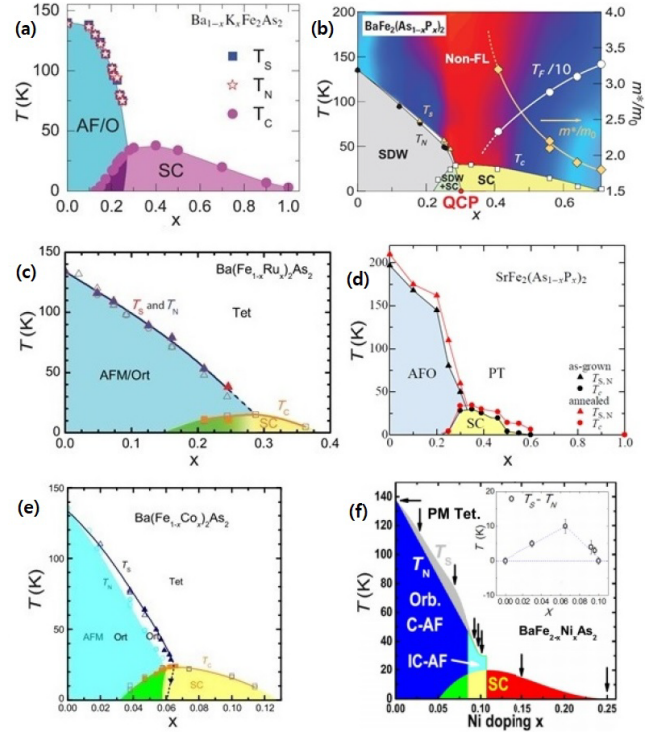


FIG. 3. (Color online) Phase diagrams of 122 family of FeSCs: (a) Hole-doped $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ [95]; (b) isovalently-doped $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ [96], (c) $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$ [97] and (d) $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$ [98]; (e) electron-doped $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ [99] and (f) $\text{Ba}(\text{Fe}_{2-x}\text{Ni}_x)\text{As}_2$ [100]. Panels (a), (c), (e), and (f): reprinted with permission from Ref. 95, 97, 99, and 100, copyright 2010, 2011, 2012 APS. Panel (b): reprinted with permission from Science, Ref. 96, copyright AAAS. Panel (d): reprinted with permission from Ref. 98, copyright JPSJ.

diagram regardless of types of chemical substitution. As an example, Fig. 3 shows phase diagrams of various 122 FeSCs: hole-doped $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ [95]; isovalently-doped $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ [96], $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$ [97], and $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$ [98]; electron-doped $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ [99] and $\text{Ba}(\text{Fe}_{2-x}\text{Ni}_x)\text{As}_2$ [100]. In all cases, the superconducting dome occurs with suppression of magnetic phase, and particularly, the maximum T_c occurs where the anti-ferromagnetic order is expected to disappear. Gradual suppression of magnetic order with composition as a tuning parameter [104] suggests the existence of the quantum critical point suggesting the close relation between magnetic fluctuations and maximum T_c . The most clear case for quantum critical scenario is found in isovalently substituted $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$, for which both in-plane and inter-plane resistivities show T -linear dependence at optimal doping [101], see the middle panel in the right column of Fig. 4. Indeed, the quantum quantum critical point is observed beneath the superconducting dome in $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ by measuring zero-temperature penetration depth [96].

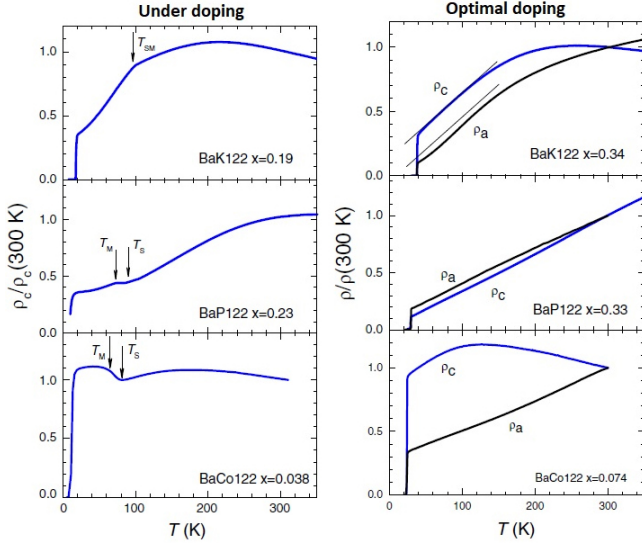


FIG. 4. (Color online) Temperature-dependent resistivity of under-doped and near optimally doped representative 122 FeSCs: $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$, $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$, and $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$. Reprinted with permission from Ref. 101, copyright 2014 APS.

However, several important differences are observed between various types of doping in both normal and superconducting state. For example, the temperature dependent resistivity shows quite distinct behavior depending on the types of chemical substitution as shown in Fig. 4 and 5. Another significant difference comes from distinct superconducting gap order parameters. While similar Fermi surfaces are found among different types of substitutions, the superconducting gap structures vary from nodal gap in $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ [96] to anisotropic full gaps in $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ [105]. More interestingly, the order parameter of $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$ [40] is known to evolve with doping from full gap ($x < 0.8$) to gap with accidental nodes for compositions $x > 0.8$ where the Lifshitz transition of Fermi surfaces occurs [106, 107]. In this section, we will review the effect of electron irradiation on six 122 FeSCs: hole-doped $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$; isovalently-doped $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$, $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$, and $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$; electron-doped $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ and $\text{Ba}(\text{Fe}_{1-x}\text{Ni}_x)_2\text{As}_2$.

B. Hole-doped $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$

$(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$ is one of the most intensively studied compounds among FeSCs due to its evolution of the superconducting gap structure over composition (x). In the optimally doped region ($x = 0.35 - 0.4$), two effective isotropic superconducting gaps were identified in various experiments, such as thermal conductivity [114], London penetration depth [108, 111], and angle-resolved photoemission spectroscopy (ARPES) [111, 115–117]. However, a gap with line nodes was identified in the heav-

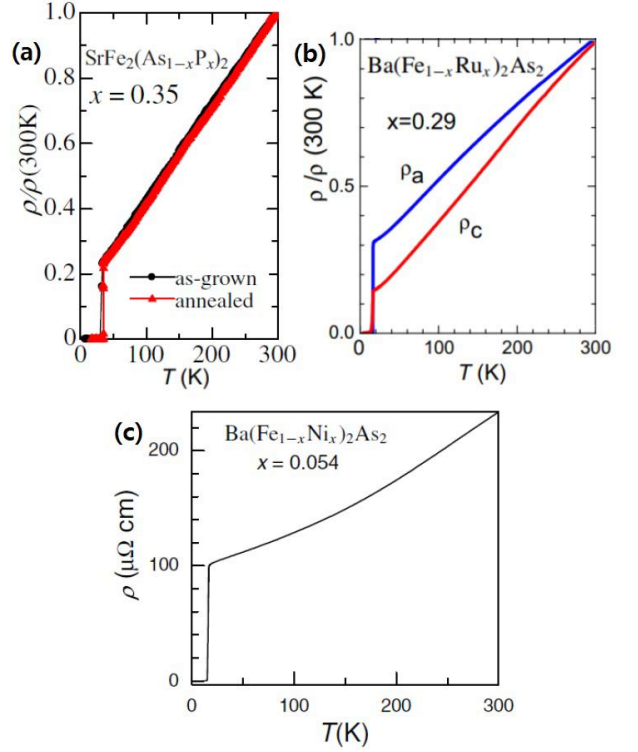


FIG. 5. (Color online) Temperature-dependent resistivity of near-optimally doped 122 FeSCs: $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$ [98], $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$ [102], $\text{Ba}(\text{Fe}_{1-x}\text{Ni}_x)_2\text{As}_2$ [103]. Panel (a): reprinted with permission from Ref. 98, copyright JPSJ. Panel (b) and (c): reprinted with permission from Ref. 102 and 103, copyright 2013, 2014 APS.

ily overdoped region ($x \geq 0.8$) from thermal conductivity [118–121], London penetration depth [122], and ARPES [115, 117]. This variation of the superconducting gap structure is likely to be connected to the Lifshitz transition near $x = 0.7 - 0.9$ where the electron-like pockets at the M point changes to hole-like pockets [106, 107]. The evolution of gap structure has been discussed in several models such as i) a crossover between two generalized s-wave states, where the usual configuration of isotropic gaps with opposite signs on the electron and hole pockets crosses over to a configuration with opposite signs on the hole pockets resulting in accidental nodes [121], ii) an intermediate time-reversal symmetry broken $s + is$ state [123], iii) a transition from $s_{\pm}$ to d wave either directly [124] or with an intermediate $s + id$ state [14, 125, 126], and iv) the existence of too-small-to-measure but finite Lilliputian gaps [127, 128].

To resolve this unusual variation, the 2.5 MeV electron irradiation in combination with resistivity and London penetration depth measurements was used by Cho *et al.* [40, 108]. First of all, the electron irradiation effectively suppresses T_c over all compositions as shown in Fig. 6. The large suppression of T_c occurs in under and over-doped compositions. For under-doped compositions shown in Fig. 7 (a), the magnetic transition temperature

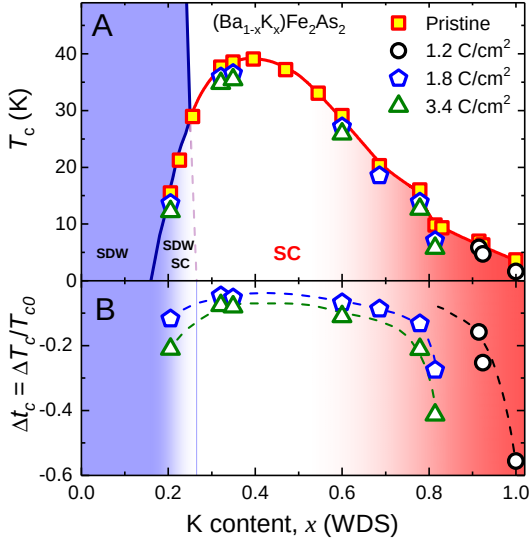


FIG. 6. (Color online) (A) T_c - x phase diagram of pristine (squares) and electron-irradiated (other symbols, see legend) samples. SDW, spin-density wave; SC, superconducting phase. (B) Normalized suppression of T_c ($\Delta T_c = \Delta T_c/T_{c0}$) versus x . Reprinted with permission from Science Advances, Ref. 40, copyright AAAS.

T_N (or T_{SM}) is also effectively suppressed in $x = 0.19$. Interestingly, the amounts of decrease of $\Delta T_c = -4.8K$ is comparable to $\Delta T_N = -5.1K$ (Fig. 7 (a)). This correlation between ΔT_c and ΔT_N also exists in another under-doped composition $x = 0.22$ as shown in Fig. 9 (b). One can test this correlation in isovalently doped $BaFe_2(As_{1-x}P_x)_2$ as will be shown later in Fig. 20, but there exists no particular correlation potentially due to the influence of the quantum critical point. For further analysis on T_c suppression in $Ba_{1-x}K_xFe_2As_2$, the changes in T_c and normalized T_c upon irradiation are summarized in Fig. 8. It clearly shows that heavily under and over-doped samples are most susceptible against irradiation.

Since the effect of irradiation varies in different materials, the dosage is not a good parameter to indicate the amount of disorder. To avoid this problem we used an increase of the normal state residual resistivity upon irradiation as a measure of disorder, which is clearly seen for example in Fig. 7. Figure 11 (a) summarizes $\Delta t_c = \Delta T_c/T_{c0}$ as a function of $\Delta\rho$.

Experimentally determined values of resistivity increase ($\Delta\rho$) and the absolute value of London penetration depth (λ_0) enable us to define dimensionless scattering rate as [68, 129]

$$g^\lambda = \frac{\hbar\Delta\rho}{2\pi k_B\mu_0 T_{c0}\lambda_0^2}, \quad (9)$$

where λ_0 is the zero temperature London penetration depth, T_{c0} is T_c before irradiation, and $\Delta\rho$ is the variation of residual resistivity. The relative change of the superconducting transition temperature $\Delta t_c = \Delta T_c/T_{c0}$

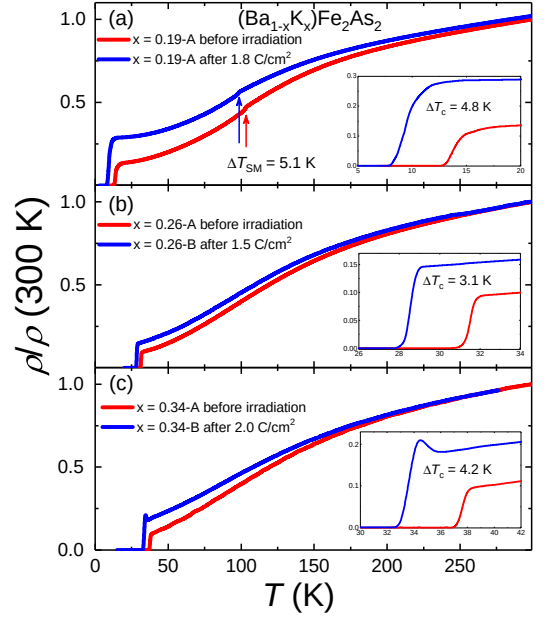


FIG. 7. (Color online) Evolution of the temperature-dependent resistivity (normalized by the value at 300 K) upon electron irradiation in $Ba_{1-x}K_xFe_2As_2$: (a) $x = 0.19$, (b) $x = 0.26$, and (c) $x = 0.34$. Reprinted from Ref. 108, copyright 2014 APS.

as a function of resistivity change $\Delta\rho$ is summarized in Fig. 11 (a). The values of λ_0 available from the literature [110–113] are plotted in Fig. 10. Since there are no reports on λ_0 in the over-doped region, we only consider the compositions with $x \leq 0.6$. Based on these parameters, the variation of reduced transition temperature $t_c = T_c/T_{c0}$ is calculated as a function of dimensionless parameter (g^λ) as shown in Fig. 11 (b). In general, t_c shows substantial decrease with increasing g^λ , but much slower than Abrikosov-Gor'kov value.

The London penetration depth was also measured for all compositions upon increasing dose of irradiation as shown in Fig. 12. In optimally doped region, the exponent of the power law fit n (bottom panel) is above 4, which is experimentally indistinguishable from exponential dependence. This is a clear signature of the full gap superconductivity. However, on moving away from the optimal doping, the exponent decreases toward $n = 2$ for the under-doped region and below $n = 2$ for over-doped region. The former finding is consistent with previous study in strongly underdoped compositions [130], interpreted as anisotropy appearing due to coexistent magnetic order [131]. The T - linear behavior of low-temperature penetration depth in the over-doped region is a signature of nodal gaps. To understand this doping dependent variation of the superconducting gap structure, a minimal two gap model is introduced to fit the penetration depths of all pristine samples (See the Sup-

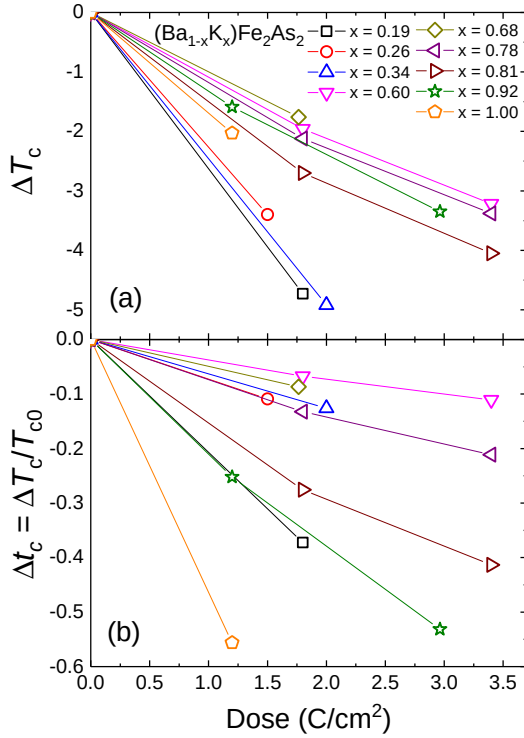


FIG. 8. (Color online) T_c suppression in $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ upon electron irradiation: (a) ΔT_c and (b) $\Delta t_c = \Delta T_c / T_{c0}$ against dosage. Data from Ref. 40 and 108.

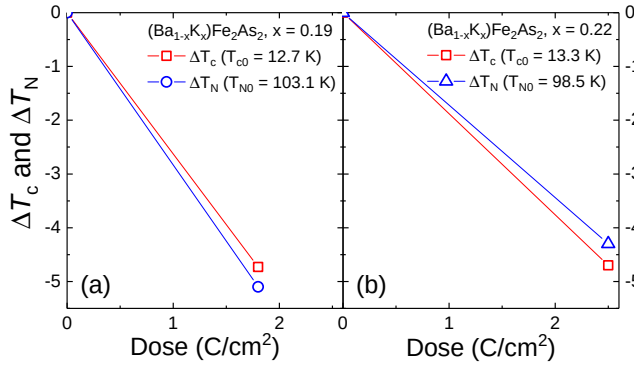


FIG. 9. (Color online) Comparison between ΔT_c and ΔT_N upon electron irradiation for $x = 0.19$ [108] and 0.22 [109] of $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$.

plementary Materials of Ref. 40 for details).

$$\Delta_1 = \Delta_{01}(1.0 + r_1 \cos 4\phi) \quad (10)$$

$$\Delta_2 = \Delta_{02}(1.0 + r_2 \cos 4\phi) \quad (11)$$

Then, the interaction potentials were calculated and the impurity scattering upon electron irradiation was treated within self-consistent t -matrix approximation. Considering the Fermi surface change near the Lifshitz transition at $x \sim 0.8$ (Figs. 13), all results of penetration depth were fitted with this model and the superconducting gap evolution was found as shown in 14. Interest-

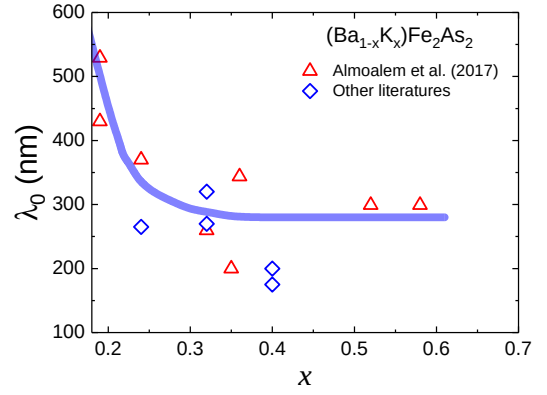


FIG. 10. (Color online) Zero-temperature penetration depth (λ_0) of $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ from literature [110–113].

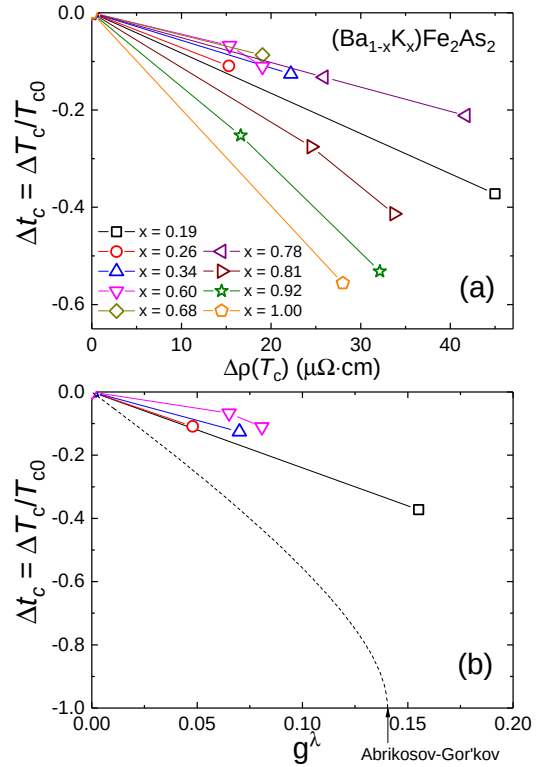
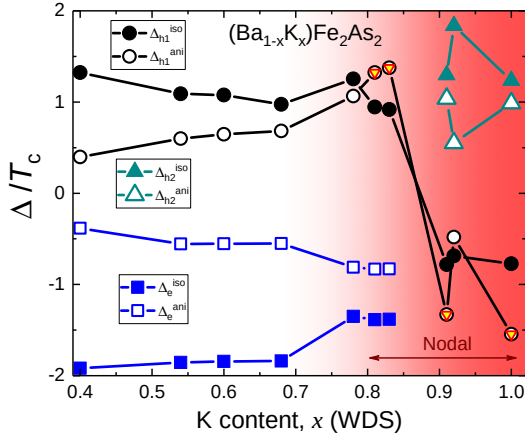
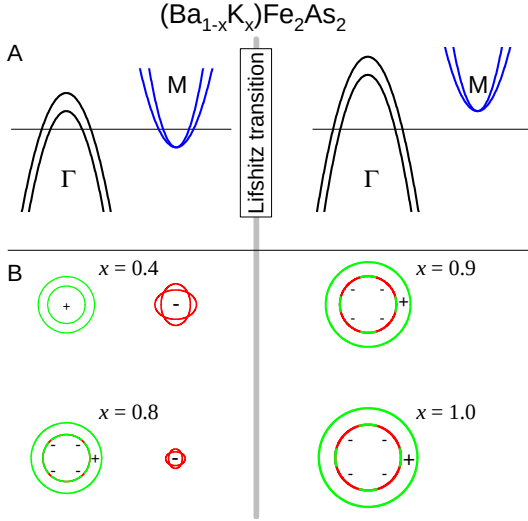


FIG. 11. (Color online) Normalized suppression, $t_c (= \Delta T_c / T_{c0})$ as functions of (a) $\Delta \rho$ and (b) g^λ . g^λ is calculated only for $x < 0.6$ where experimental λ_0 is available from literatures.

ingly, all experimental data are well explained assuming that the sign-change between hole and electron pockets (near optimal doped region) varies to sign-change within the same hole pockets in heavily over-doped region. This clearly supports that the nodes observed in $x > 0.8$ is not symmetry imposed but accidental nodes, which is consistent with various other experimental observations.



parameter is calculated and plotted in Fig. 19 (b). In general, the suppression of t_c is similar among different compositions. More interestingly, these values are very close to Abrikosov-Gor'kov value. Another interesting fact is shown in Fig. 20 that suppression rates of ΔT_N of under-doped compositions ($x = 0, 0.16, 0.24$,

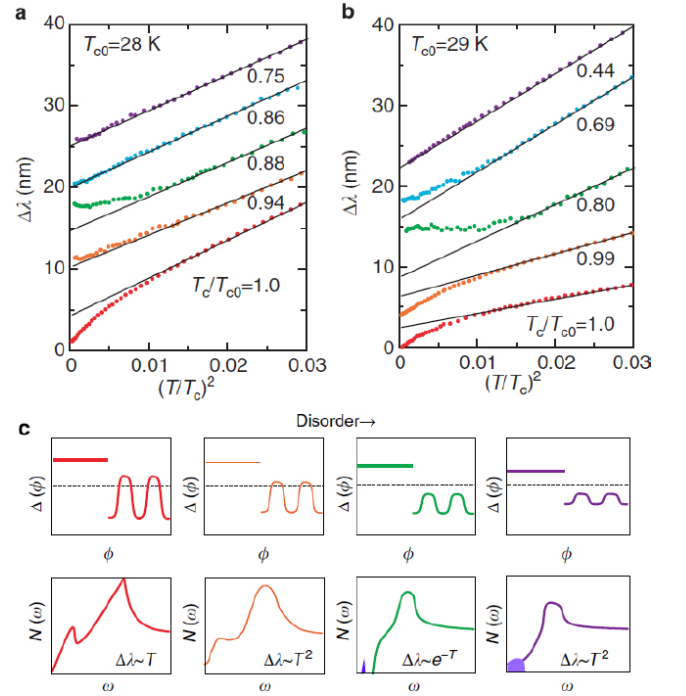


FIG. 15. (Color online) Effect of electron irradiation on the low-temperature penetration depth $\Delta\lambda$ of two samples of $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$: (a) $T_{c0} = 28$ K and (b) $T_{c0} = 29$ K. Each curve is shifted vertically for clarity. Lines are the T^2 dependence fits at high temperatures. (c) Schematic of $s_{\pm}$ order parameter versus azimuthal angle ϕ (top row) and density of states N versus energy ω (bottom row) with increasing irradiation dosage (from the left to right). Reprinted with permission from Nature Communications, Ref. 39, copyright Macmillan Publishers Ltd.

0.28) are very similar. The reason of these similar rates suppression requires further studies. Unlike hole-doped $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$, ΔT_c is not comparable to ΔT_N , potentially due to the presence and shift of quantum criticality point.

D. Isovalently substituted $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$

Similar to other substitutions in 122 family FeSCs, isovalent ruthenium substitution on iron-site of BaFe_2As_2 also suppresses long-range magnetic order and induces superconductivity with range of bulk coexistence, see composition phase diagram in Fig. 3 (c). Unlike the electron-doped FeSCs, the structural and magnetic transitions remain coincident in temperature. The compensation condition between hole and electron carriers doesn't change in this compound [135–138]. Since the quantum critical point was discovered in nodal-gap superconductor $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$, it is interesting to see the effect of Ru-substitution as another isovalently substituted compound.

Prozorov *et al.* conducted *in-situ* and *ex-situ* mea-

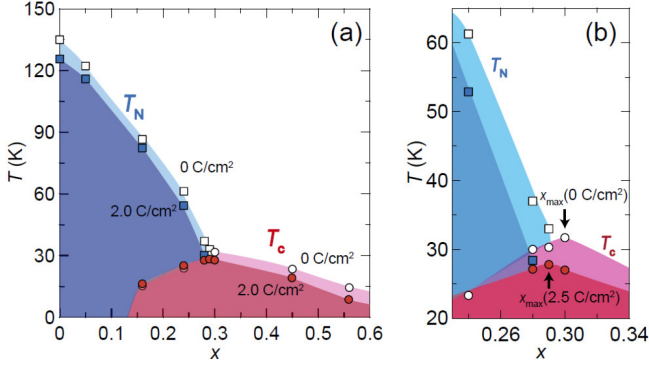


FIG. 16. (Color online) (a) The doping phase diagram of $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ for 0 and 2.0 C/cm^2 of electron irradiations. (b) The zoom of the region of near optimally doped composition for 0 and 2.5 C/cm^2 . The arrow (maximum T_c) moves toward lower composition indicating the shift of superconducting dome upon irradiation. Reprinted with permission from Ref. 132, copyright JPSJ.

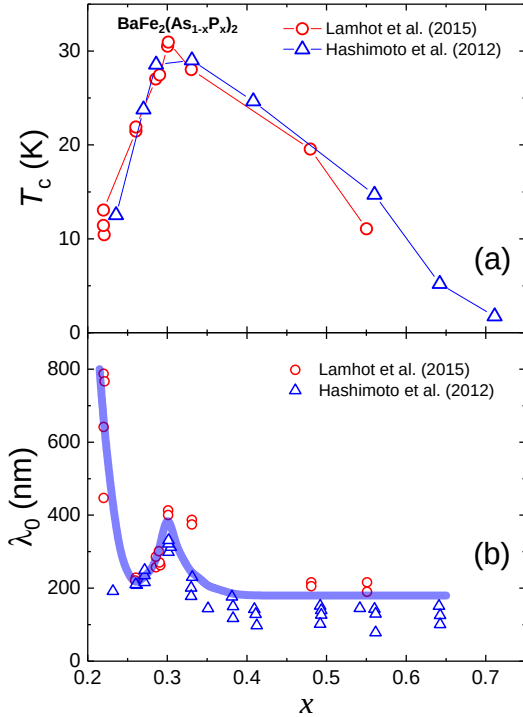


FIG. 17. (Color online) (a) T_c and (b) zero-temperature penetration depth λ_0 versus x in $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$. Data from Ref. 96 and 133

measurements of the resistivity in a slightly under-doped single crystal of $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$ ($x = 0.24$) with increasing dose of 2.5 MeV electron irradiation as shown in Fig. 21. The suppression of T_c is summarized in Fig. 22. Furthermore, the dimensionless scattering rate g^λ is calculated following equation 9 and plotted in Fig. 23. In general, the rapid suppression of T_c is observed, which cannot be explained by s_{++} scenario, but supports $s_{\pm}$ pairing mechanism. The rate of suppression is much

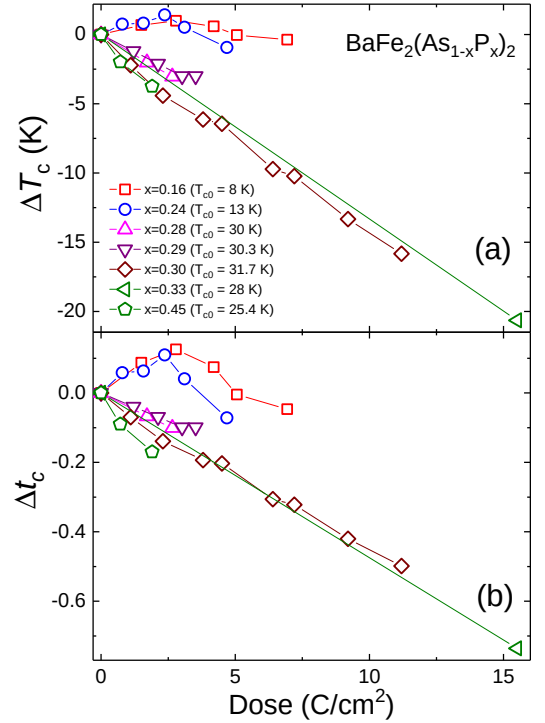


FIG. 18. (Color online) Suppression of T_c : (a) ΔT_c and (b) $\Delta t_c = \Delta T_c/T_{c0}$ of $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ upon electron irradiation. Data from Ref. 132. Data of $x = 0.25$ and 0.33 , and extended data of $x = 0.30$ (dose $> 6.4 \text{ C}/\text{cm}^2$) are directly obtained by authors of Ref. 132 and presented with permission.

slower than that of $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$.

E. $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$

The phase diagram of another 122 compound with isovalent substitution, $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$, with the maximum value of $T_c \sim 30 \text{ K}$, is very similar to $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ (Fig. 3 (d)). In particular, it also shows the nodal superconducting gaps [139, 140]. Specific heat and NMR studies are consistent with the nodal small gap and nodeless large gaps [139]. According to the analysis of the low-temperature behavior of the London penetration depth, the superconducting gap of $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$ is consistent with the presence of line nodes in the gap [140], very similar to $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$.

In order to understand the origin of nodal gap, Strehlow *et al.* studied the effect of electron irradiation by measuring the London penetration depth before and after irradiation [69]. As shown in Fig. 24, the electron irradiation effectively suppressed T_c of optimally doped $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$ ($x = 0.35$). Upon irradiation, the low-temperature penetration depth shows increase of the power-law exponent (n). Interestingly, this exponent exceeds the value of $n = 2$ (Fig. 25) suggesting that the nodes in superconducting gap are of accidental type, not

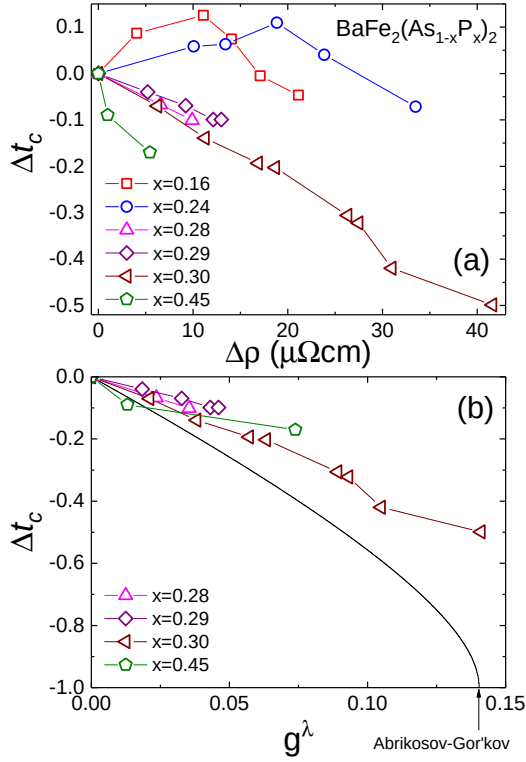


FIG. 19. (Color online) $\Delta t_c = \Delta T_c/T_{c0}$ of $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ versus (a) $\Delta\rho$ [132] and (b) the dimensionless scattering parameter (g^λ) calculated following equation 9. The solid line is from Abrikosov-Gor'kov calculation.

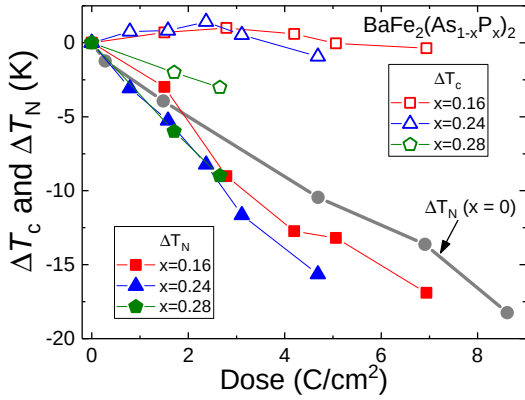


FIG. 20. (Color online) Comparison between ΔT_c and ΔT_N upon electron irradiation. Data from Ref. 132. Data of $x = 0.25$ are directly obtained by authors in Ref. 132 and presented with permission.

symmetry-imposed. In Fig. 26, the ΔT_c and $\Delta T_c/T_{c0}$ are plotted against dose of irradiation only for sample A (higher T_c , clean sample). This will be compared with other 122 compounds later in the section of discussion. Due to lack of resistivity data, g^λ is not calculated.

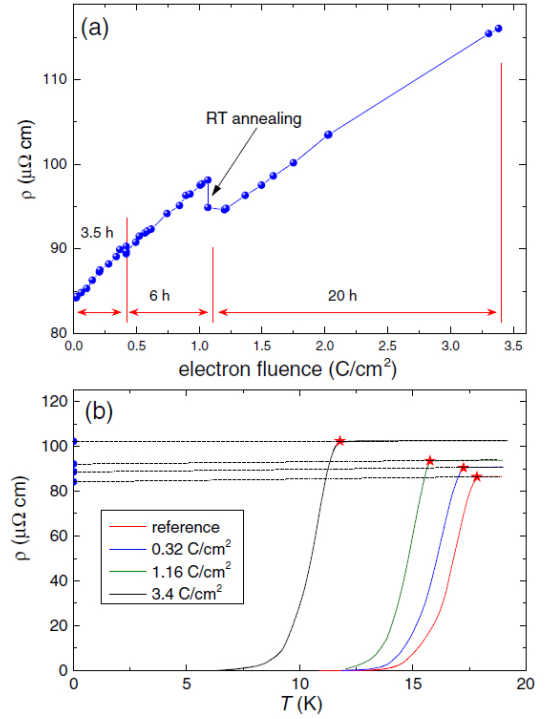


FIG. 21. (Color online) (a) The *in-situ* measurements of resistivity in $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$ ($x = 0.24$) at $T \approx 22\text{K}$ as a function of the irradiation dose. The breaks in the curve correspond to the extraction of the sample and warming it up to room temperature resulting in a partial annealing of the defects. (b) The *ex-situ* measurements of resistivity versus temperature between the irradiation runs. Dashed lines show linear extrapolation of $\rho(T)$ from above T_c to $T = 0\text{K}$. Reprinted with permission from Ref. 68, copyright 2014 APS.

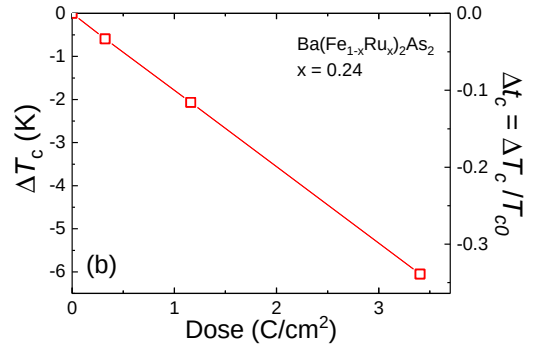


FIG. 22. (Color online) Suppression of T_c : ΔT_c (left) and $\Delta t_c = \Delta T_c/T_{c0}$ (right) of $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$ ($x = 0.24$) upon electron irradiation. Data from Ref. 68.

F. Electron-doped $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$

The competition between superconductivity and magnetic phase has been intensively investigated in electron-doped $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ [6-8]. A clear separation between the temperatures of structural transition (T_s) and the magnetic phase transition (T_N) with doping is found,

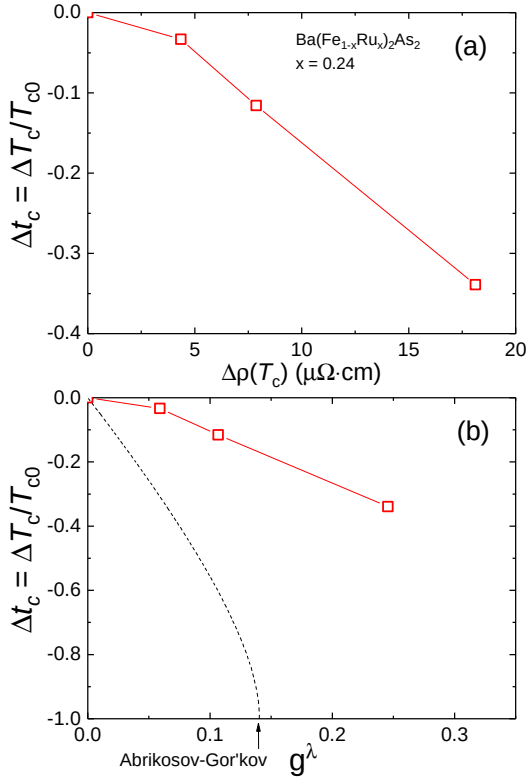


FIG. 23. (Color online) (a) $\Delta t_c = \Delta T_c/T_{c0}$ versus $\Delta\rho$ of $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$ ($x = 0.24$) upon electron irradiation. The dimensionless scattering rate g^λ is calculated from resistivity and the penetration depth following equation 9. Here $\lambda_0 = 200$ nm was used. Abrikosov-Gor'kov calculation is also shown for comparison. Data from Ref. 68.

as shown in Fig. 3 (e) [99], which is different from the compounds with hole-doping and isovalent substitution.

The effect of electron irradiation on $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ was mainly investigated by van der Beek *et al.* [141]. The electron irradiation effectively suppresses T_c of $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ as shown in Fig. 27. The largest suppression occurs in heavily under-doped and over-doped regions in which gap is strongly anisotropic and nodal [142, 143]. The suppression is the weakest near the optimal doping region similar to other 122 compounds. Since there are no reports on variation of resistivity upon electron irradiation for various compositions, van der Beek *et al.* estimated the scattering parameter ($z\Gamma/2\pi T_c$) based on the density of states, effective mass, atomic point defect density, scattering angle, and so on (See details in Ref. 141). While van der Beek *et al.* mentioned that $\delta R/R \sim 0.05[\text{C cm}^{-2}]^{-1}$, the actual variations of resistivity ($\Delta\rho$) are not available for all compositions. Nakajima *et al.* estimated the dimensionless parameter based on $\Delta\rho$ by proton irradiation which is likely to result from clusters of defects instead of point defects [61]. Since we limit our scope to electron irradiation, g^λ of $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ is not estimated.

Van der Beek *et al.* also used microwave cavity per-

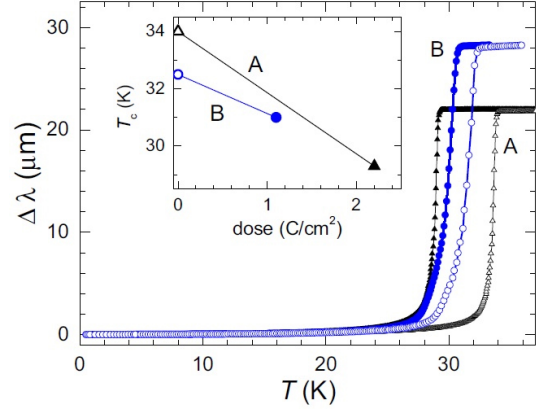


FIG. 24. (Color online) Full temperature range variation of $\Delta\lambda(T)$, in two single crystals of $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$, $x = 0.35$, A (black triangles) and B (blue circles) before (open symbols) and after (solid symbols) electron irradiation with doses of 2.2 and 1.1 C/cm^2 , respectively. The inset shows the change of T_c as a function of the irradiation dose. Reprinted with permission from Ref. 69, copyright 2014 APS.

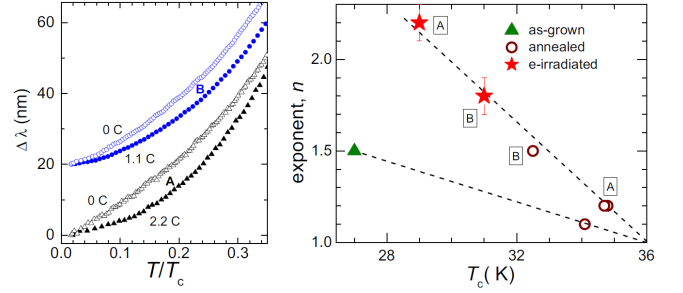


FIG. 25. (Color online) (a) Low-temperature variation of $\Delta\lambda$ in $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$ ($x = 0.35$) versus reduced temperature T/T_c . The data before and after irradiation are shown in open and solid symbols, respectively. Offset of 20 nm is applied to avoid overlapping. (b) The exponent n of the power-law fit of $\Delta\lambda$. Note the significantly smaller exponents for as-grown and annealed compared to the samples with irradiation defects. Reprinted with permission from Ref. 69, copyright 2014 APS.

turbation technique to measure surface impedance, and studied the variation of the superfluid density of the optimally doped $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ ($x = 0.075$) upon electron irradiation in Fig. 28. The normalized frequency shift, which is proportional to the superfluid density $n_s \propto \lambda^{-2}$, shows little to no change upon irradiation while T_c drops by 10 %. This suggests that the isotropic superconducting gaps with $s_\pm$ -pairing symmetry are intact upon irradiation.

G. Electron-doped $\text{Ba}(\text{Fe}_{1-x}\text{Ni}_x)_2\text{As}_2$

$\text{Ba}(\text{Fe}_{1-x}\text{Ni}_x)_2\text{As}_2$ is an electron-doped 122 FeSC [144] in which every Ni donates two electrons in contrast to Co substitution that donates only one electron [145]. Similar

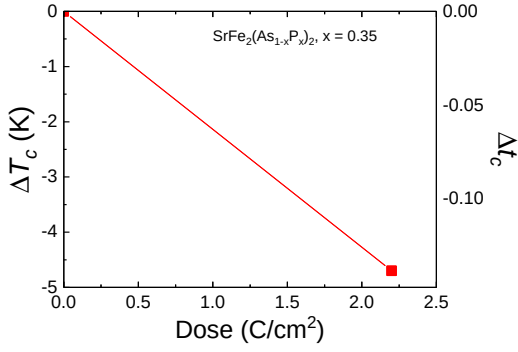


FIG. 26. (Color online) Suppression of T_c : ΔT_c (left) and $\Delta t_c = \Delta T_c / T_{c0}$ (right) of SrFe₂(As_{1-x}P_x)₂ ($x = 0.35$) upon electron irradiation. The sample A with higher T_c is plotted. Data from Ref. 69.

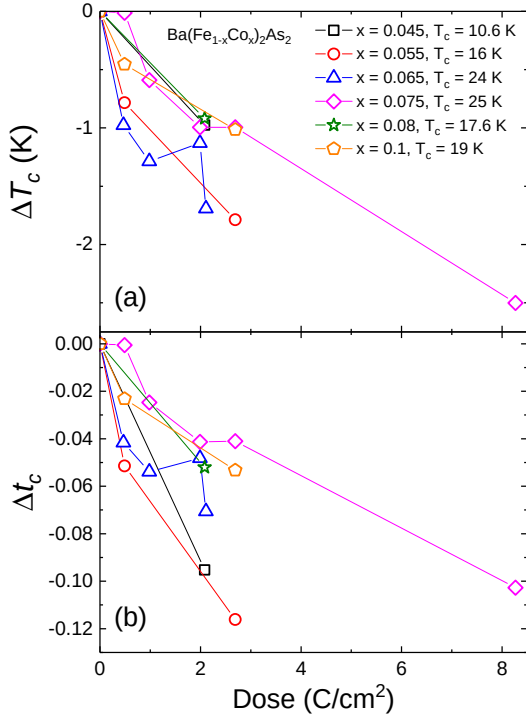


FIG. 27. (Color online) Suppression of T_c : (a) ΔT_c and (b) $\Delta t_c = \Delta T_c / T_{c0}$ versus irradiation dose in Ba(Fe_{1-x}Co_x)₂As₂. Data from Ref. 141.

to other iron - based superconductors, Ba(Fe_{1-x}Ni_x)₂As₂ system shows a superconducting dome with the total suppression of static AF order near the optimal doping level $x \sim 0.5$ [100]. As commonly found in electron-doped systems, the separation between structural (T_s) and magnetic (T_m) transitions is also observed in this compound. However, the details vary among various studies. High-resolution synchrotron x-ray and neutron scattering study shows sharp first-order like disappearance of magnetic ordering above the optimally doped region, and the authors interpreted it as an avoidance of quantum criticality [146] as shown in Fig. 3 (f). In NMR

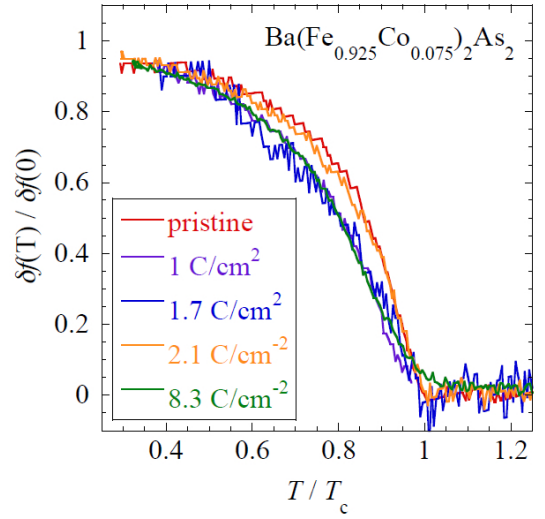


FIG. 28. (Color online) Superfluid density of Ba(Fe_{1-x}Co_x)₂As₂ ($x = 0.075$) upon electron irradiation by using microwave cavity perturbation technique. Reprinted with permission from Ref. 141, copyright IOP.

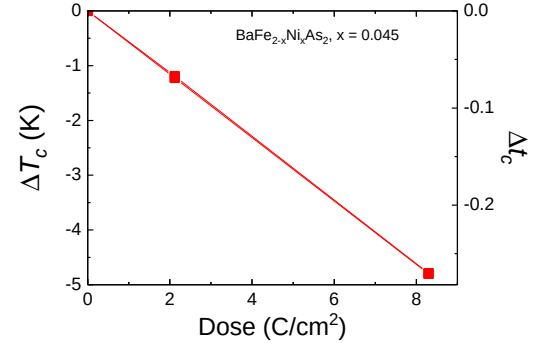


FIG. 29. (Color online) Suppression of T_c : ΔT_c (left) and $\Delta t_c = \Delta T_c / T_{c0}$ (right) versus dose of BaFe_{2-x}Ni_xAs₂. Data from Ref. 141.

study, the separation was interpreted as an evidence of two critical points at $x_{c1} = 0.05$ and $x_{c2} = 0.07$, respectively. Since the highest T_c is found around x_{c1} , it is claimed that the superconductivity is more closely tied to the magnetic quantum critical point.

The effect of electron irradiation on Ba(Fe_{1-x}Ni_x)₂As₂ ($x = 0.045$) was studied by van der Beek *et al.* [141]. The suppression of T_c is shown in Fig. 29. Since the resistivity data are not available, the dimensionless parameter (g^λ) is not estimated.

IV. DISCUSSION

In this section, we summarize and compare the T_c suppression rates upon electron irradiation of various 122 FeSCs. We use the normalized transition temperature $t_c = T_c / T_{c0}$, where T_{c0} is the value in pristine samples.

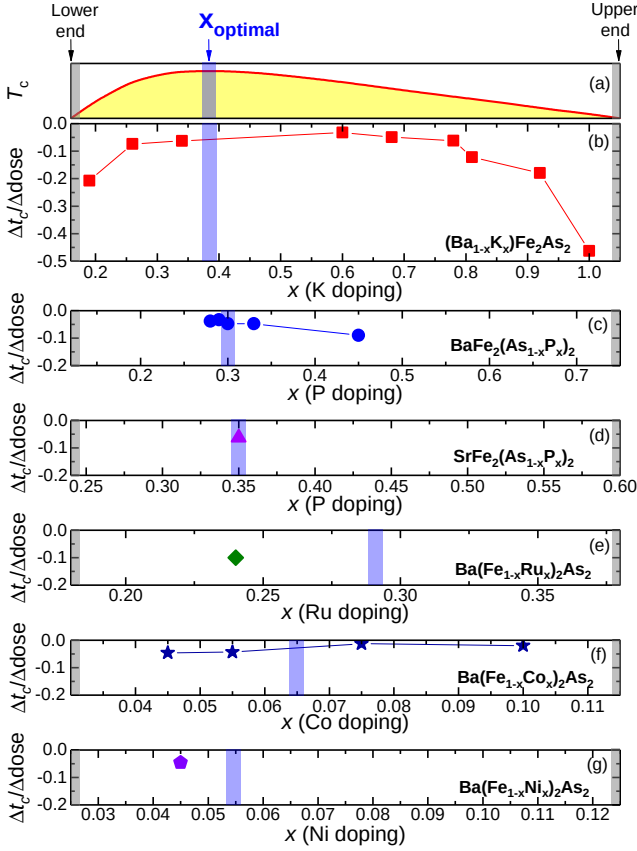


FIG. 30. (Color online) $\Delta t_c/\Delta \text{dose}$ versus x of 122 FeSCs. (a) Schematic $T_c - x$ phase diagram. (b) - (g) $\Delta t_c/\Delta \text{dose}$ versus x of $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$, $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$, $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$, $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$, $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$, and $\text{Ba}(\text{Fe}_{1-x}\text{Ni}_x)_2\text{As}_2$, respectively. Note that the blue shaded area indicates the optimally doped composition (x_{optimal}) with maximum T_c for all panels. Approximate upper and lower ends of superconducting dome ($T_c = 0$) are marked as gray shaded area.

In Fig. 30 we compare $\Delta t_c/\Delta \text{dose}$ versus x of all six compounds. For convenience of comparison, the range of x is limited to superconducting compositions only. The schematic $T_c - x$ phase diagram is shown in panel (a) with marks of optimally doped region (blue shaded area) and two ends of the superconducting dome (gray shaded area). For panels (b) - (g), both ends with gray area are the end compositions of superconducting dome, and blue area indicates the optimally doped composition. Systematic studies that cover more than 50 % of superconducting composition are only available for $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$ and $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$. For the case of $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$, the value of $\Delta t_c/\Delta \text{dose}$ is small near optimal doping, and becomes larger as it goes toward under and over-doped compositions. In particular, the pure KFe_2As_2 shows the largest value, $\Delta t_c/\Delta \text{dose} \approx 0.5$. However, the $\Delta t_c/\Delta \text{dose}$ of $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ in panel (f) is small (< 0.05), and doesn't change much with compositions. These small values can be attributed

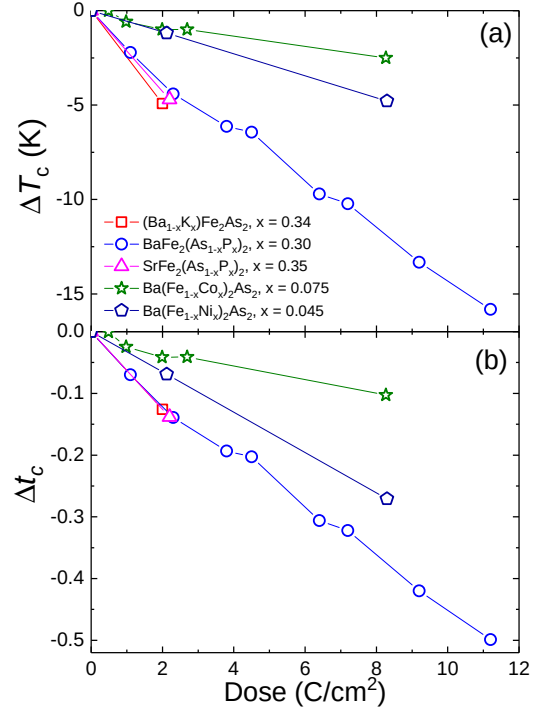


FIG. 31. (Color online) Suppression of T_c : (a) ΔT_c and (b) $\Delta t_c = \Delta T_c/T_{c0}$ upon electron irradiation in optimally doped 122 FeSCs.

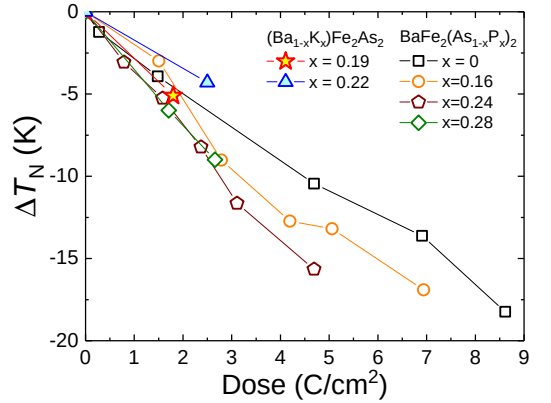


FIG. 32. (Color online) Comparison of ΔT_N upon electron irradiation in under-doped $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$ and $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$.

to the fact that the pristine $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ is already in the dirty limit as shown in Fig. 4, so additional disorder introduced by electron irradiation is less effective in changing its properties. For $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$, only near optimal and slightly over doped compositions were studied. While the doping dependence of $\Delta t_c/\Delta \text{dose}$ is similar to $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$, the comparison is not conclusive due to the limited range of composition studied. Studies for singular compositions were only performed for $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$ and $\text{Ba}(\text{Fe}_{1-x}\text{Ni}_x)_2\text{As}_2$, so further studies are needed to find their doping dependence.

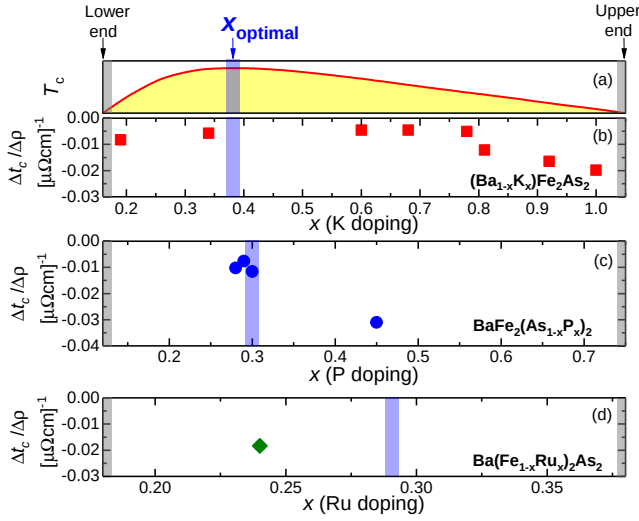


FIG. 33. (Color online) $\Delta t_c/\Delta\rho$ versus compositions of 122 FeSCs. (a) Schematic $T_c - x$ phase diagram. (b) - (d) $\Delta t_c/\Delta\rho$ versus x in $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$, $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$, and $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$, respectively. Note that the blue shaded area indicates the optimally doped composition (x_{optimal}) with maximum T_c for all panels. Approximate upper and lower ends of superconducting dome ($T_c = 0$) are marked as gray shaded area.

Another interesting aspect in Fig. 30 is that in general the optimally doped compositions of all 122 FeSCs commonly show lowest suppression with similar low values (< 0.05). To get additional insight into this fact, the data for only optimally doped compositions are replotted in Fig. 31 (a) ΔT_c and (b) $\Delta t_c = \Delta T_c/T_{c0}$ versus increasing dosage. Two different trends of T_c suppression are observed, panel (a). The first group includes hole-doped and isovalent substituted compounds: $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$, $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$, $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$, and $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$. The second group includes electron doped compounds: $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ and $\text{Ba}(\text{Fe}_{1-x}\text{Ni}_x)_2\text{As}_2$. The former group commonly shows suppression rate of $\Delta T_c = -4 \text{ K [C/cm]}^{-1}$, regardless of different T_c and different chemical contents. The reason why these different compounds show similar suppression behavior in absolute Kelvin scale remains unclear. For the latter group of electron doped compounds, the rate is about three times smaller. This slow suppression of T_c in electron doped compounds can be understood by the fact that the pristine samples are already in the dirty limit as clearly seen in resistivity measurement in the bottom panels of Fig. 4.

In addition to ΔT_c , Fig. 32 shows comparison of ΔT_N for under-doped $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$ and $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$. Interestingly, these different compounds show similar suppression rates upon electron irradiation even though their T_{N0} are notably different as well as chemical contents. This can be an indication that scattering mechanism in SDW phase are similar producing similar response upon electron irradiation.

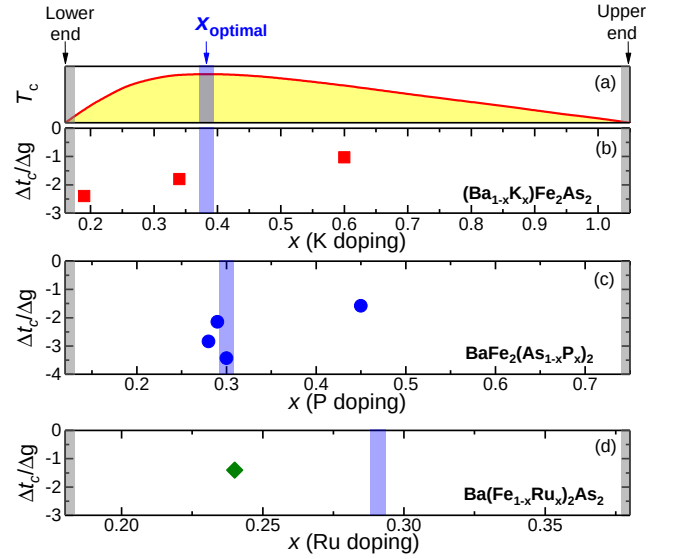


FIG. 34. (Color online) $\Delta t_c/\Delta g$ versus x of 122 FeSCs. (a) Schematic T_c versus x phase diagram. (b)-(d) $\Delta t_c/\Delta g$ versus x in $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$, $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$, and $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$, respectively. Note that the blue shaded area indicates the optimally doped composition (x_{optimal}) with maximum T_c for all panels. Approximate upper and lower ends of superconducting dome ($T_c = 0$) are marked as gray shaded area.

In Fig. 33, the suppression rates per resistivity increase ($t_c/\Delta\rho$) in $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$, $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$, and $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$ are summarized. The panel (a) of $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$ shows a rather complete doping dependence. The largest value of $t_c/\Delta\rho$ is obtained in the pure KFe_2As_2 , and the smallest value in the near-optimally doped compounds. In general, the value of $t_c/\Delta\rho$ increases away from the optimally doped composition. The similar trend is observed in $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$, but the further experimental data in over and under doped compositions are needed. In $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$, only one underdoped data result is available, which is comparable to those of underdoped $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$ and $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$.

In Fig. 34, $\Delta t_c/\Delta g$ of three compounds in Fig. 33 is summarized. In $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$ (panel (b)), the most under doped compound shows the largest value, then weakens toward near-optimal and slightly over-doped region. Since λ_0 values are not available for over doped region, dimensionless parameter g^λ in over doped region is not estimated. In general, one can find that $\Delta t_c/\Delta g$ of $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$ has larger values for most of compositions than those of $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$. For further comparison, the Δt_c versus g^λ of near optimally doped region is plotted in Fig. 35 (b). It is clear that the suppression of T_c is larger in $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$. However, in all cases, the suppression rate is slower than the Abrikosov-Gor'kov value.

In Fig. 36, the key parameters of optimally doped 122 FeSCs are summarized. Panel (a) shows T_c of all com-

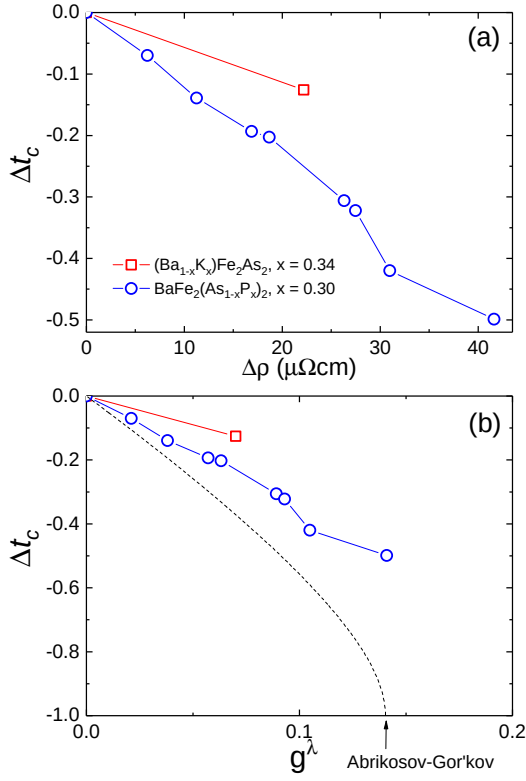


FIG. 35. (Color online) Comparison of optimally doped $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ and $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$ compounds: (a) Δt_c versus $\Delta \rho$ and (b) Δt_c versus the dimensionless scattering parameter (g^λ) calculated following equation 9.

pounds ranging the highest value in $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$, and the lowest in $\text{Ba}(\text{Fe}_{1-x}\text{Ni}_x)_2\text{As}_2$. Since the initial resistivity values (as an initial disorder before irradiation) are important to understand the post-irradiated properties, ρ_0 at 40 K for pristine samples are compared in panel (b). $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$, $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$, and $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$ have rather low resistivity values ($< 50 \mu\Omega\text{cm}$) while electron-doped $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ and $\text{Ba}(\text{Fe}_{1-x}\text{Ni}_x)_2\text{As}_2$ have quite large values ($> 100 \mu\Omega\text{cm}$) indicating that they are already in dirty limit at pristine state. In panel (c), the values of $\Delta T_c/\text{dose}$ are compared. In general, the electron-doped compounds ($\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ and $\text{Ba}(\text{Fe}_{1-x}\text{Ni}_x)_2\text{As}_2$) have the least change upon electron irradiation mainly due to pre-existing disorder (dirty limit), while hole-doped and isovalent-substituted compounds show larger change. In panel (d), $\Delta t_c/\text{dose}$ of $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$, $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$, and $\text{SrFe}_2(\text{As}_{1-x}\text{P}_x)_2$ shows similar values, while $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ has the smallest value. In panel (e), $\Delta T_c/\text{dose}$ is only shown for $(\text{Ba}_{1-x}\text{K}_x)\text{Fe}_2\text{As}_2$ and $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$. It is clear that the suppression is stronger in $\text{BaFe}_2(\text{As}_{1-x}\text{P}_x)_2$.

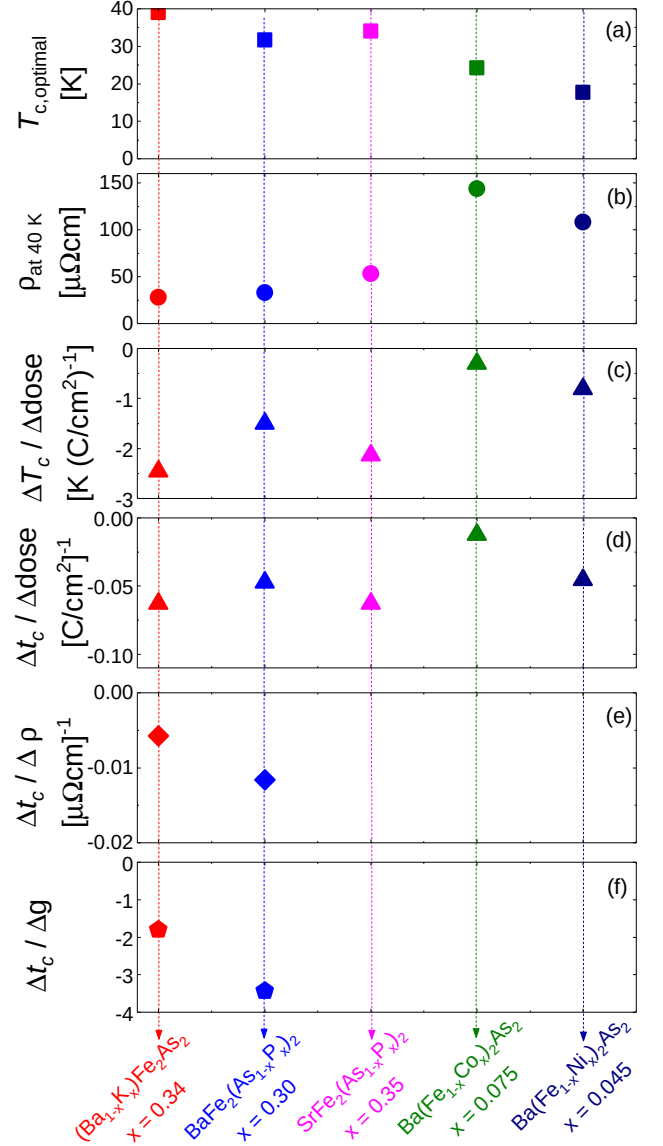


FIG. 36. (Color online) Summary of key parameters in optimally-doped 122 FeSCs: (a) T_c , (b) ρ at 40 K, (c) $\Delta T_c/\Delta \text{dose}$, (d) $\Delta t_c/\Delta \text{dose}$, (e) $\Delta t_c/\Delta \rho$, and (f) $\Delta t_c/\Delta g$.

V. CONCLUSIONS

In this article, we reviewed the use of electron irradiation that induces controlled point - like disorders as a phase sensitive probe to study superconductivity in the 122 family of iron - based superconductors. The simultaneous measurements of the changes in the superconducting transition temperature and low - temperature variation of the London penetration depth lead to the experimental conclusion that $s_{\pm}$ pairing is robust and ubiquitous in iron - based superconductors. Substantial sensitivity to non-magnetic disorder also means that all experimental studies of the superconducting gap struc-

ture should be analyzed taking the effect of impurity scattering into account. While the material may be “clean” in terms of comparison of normal mean free path and very short coherence length, the pairbreaking is significant at any concentration of scattering centers. This will affect temperature dependence of all thermodynamic, spectroscopic and transport properties.

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